

WHAT IS CLAIMED IS:

1. A semiconductor light-emitting device constituted by mounting a semiconductor light-emitting element on a base substance, wherein

the semiconductor light-emitting element has outgoing light having an emission wavelength of 390 to 420 nm; and

there is included a fluorescent substance that is excited by outgoing light from the semiconductor light-emitting element and emits red light having an emission wavelength with its main emission peak in a wavelength range of 600 to 670 nm.

2. The semiconductor light-emitting device according to Claim 1, wherein the fluorescent substance is composed of any one or more selected from a fluorescent substance group consisting of:

M_2O_2S : Eu (M is any one or more elements selected from La, Gd and Y);

$0.5 MgF_2 \cdot 3.5MgO \cdot GeO_2$: Mn;

Y_2O_3 : Eu;

$Y(P, V) O_4$: Eu; and

YVO_4 : Eu.

3. A semiconductor light-emitting device constituted by mounting a semiconductor light-emitting element on a base substance, wherein

the semiconductor light-emitting element has outgoing light having an emission wavelength in a range of 390 to 420 nm; and

there is included a fluorescent substance that is excited by outgoing light from the semiconductor light-emitting element and emits green light having an emission wavelength with its main emission peak in a wavelength range of 500 to 540 nm.

4. The semiconductor light-emitting device according to Claim 3, wherein the fluorescent substance is composed of any one or more selected from a fluorescent substance group consisting of:

$\text{RMg}_2\text{Al}_{16}\text{O}_{27}$: Eu, Mn (R is any one or both elements selected from Sr and Ba);

$\text{RMgAl}_{10}\text{O}_{17}$: Eu, Mn (R is any one or both elements selected from Sr and Ba);

ZnS : Cu;

SrAl_2O_4 : Eu;

SrAl_2O_4 : Eu, Dy;

ZnO : Zn;

$\text{Zn}_2\text{Ge}_2\text{O}_4$: Mn;

Zn_2SiO_4 : Mn; and

$\text{Q}_3\text{MgSi}_2\text{O}_8$: Eu, Mn (Q is any one or more elements selected from Sr, Ba and Ca).

5. A semiconductor light-emitting device constituted

by mounting a semiconductor light-emitting element on a base substance, wherein

the semiconductor light-emitting element has outgoing light having an emission wavelength in a range of 390 to 420 nm; and

there is included a fluorescent substance that is excited by outgoing light from the semiconductor light-emitting element and emits blue light having an emission wavelength with its main emission peak in a wavelength range of 410 to 480 nm.

6. The semiconductor light-emitting device according to Claim 5, wherein the fluorescent substance is composed of any one or more selected from a fluorescent substance group consisting of:

$A_{10}(PO_4)_6Cl_2:Eu$ (A is any one or more elements selected from Sr, Ca, Ba, Mg and Ce);

$XMg_2Al_{16}O_{27}:Eu$ (X is any one or both elements selected from Sr and Ba);

$XMgAl_{10}O_{17}:Eu$ (X is any one or both elements selected from Sr and Ba);

$ZnS:Ag$;

$Sr_{10}(PO_4)_6Cl_2:Eu$;

$Ca_{10}(PO_4)_6F_2:Sb$;

$Z_3MgSi_2O_8:Eu$ (Z is any one or more elements selected from Sr, Ca and Ba);

$\text{SrMgSi}_2\text{O}_8 : \text{Eu};$

$\text{Sr}_2\text{P}_2\text{O}_7 : \text{Eu};$ and

$\text{CaAl}_2\text{O}_4 : \text{Eu}, \text{Nd}.$

7. A semiconductor light-emitting device constituted
5 by mounting a semiconductor light-emitting element on a
base substance, wherein

the semiconductor light-emitting element has
outgoing light having an emission wavelength in a range of
390 to 420 nm; and

10 there is included a fluorescent substance that is
excited by outgoing light from the semiconductor light-
emitting element and emits blue green light having an
emission wavelength with its main emission peak in a
wavelength range of 480 to 500 nm.

15 8. The semiconductor light-emitting device according
to Claim 7, wherein the fluorescent substance is composed
of any one or more selected from a fluorescent substance
group consisting of:

$\text{Sr}_4\text{Al}_{14}\text{O}_{25} : \text{Eu};$

20 $\text{Sr}_4\text{Al}_{14}\text{O}_{25} : \text{Eu}, \text{Dy};$

$\text{L}_{10}(\text{PO}_4)_6\text{Cl}_2 : \text{Eu}$ (L is any one or more elements
selected from Ba, Ca and Mg); and

$\text{Sr}_2\text{Si}_3\text{O}_8 \cdot 2\text{SrCl}_2 : \text{Eu}.$

9. A semiconductor light-emitting device constituted
25 by mounting a semiconductor light-emitting element on a

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base substance, wherein

the semiconductor light-emitting element has outgoing light having an emission wavelength in a range of 390 to 420 nm; and

5 there is included a fluorescent substance that is excited by outgoing light from the semiconductor light-emitting element and emits orange light having an emission wavelength with its main emission peak in a wavelength range of 570 to 600 nm.

10 10. The semiconductor light-emitting device according to Claim 9, wherein the fluorescent substance is composed of any one or more selected from a fluorescent substance group consisting of:

ZnS: Mn; and

15 ZnS: Cu, Mn, Co.

11. The semiconductor light-emitting device according to Claim 1, wherein

20 a sealing resin for sealing at least a part of the base substance and the semiconductor light-emitting element is included; and

the sealing resin contains the fluorescent substance.

12. The semiconductor light-emitting device according to Claim 3, wherein

25 a sealing resin for sealing at least a part of

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the base substance and the semiconductor light-emitting element is included; and

the sealing resin contains the fluorescent substance.

5 13. The semiconductor light-emitting device according to Claim 5, wherein

a sealing resin for sealing at least a part of the base substance and the semiconductor light-emitting element is included; and

10 the sealing resin contains the fluorescent substance.

14. The semiconductor light-emitting device according to Claim 7, wherein

15 a sealing resin for sealing at least a part of the base substance and the semiconductor light-emitting element is included; and

the sealing resin contains the fluorescent substance.

20 15. The semiconductor light-emitting device according to Claim 9, wherein

a sealing resin for sealing at least a part of the base substance and the semiconductor light-emitting element is included; and

25 the sealing resin contains the fluorescent substance.

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16. The semiconductor light-emitting device according to Claim 11, wherein

the base substance is a lead frame having a cup-shaped mount section;

5 the semiconductor light-emitting element is disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding; and

10 at least a part of the two lead frames and the semiconductor light-emitting element are sealed with the sealing resin.

17. The semiconductor light-emitting device according to Claim 11, wherein

15 the base substance is an insulator connected to ends of a pair of lead frames;

the semiconductor light-emitting element is connected to metallic wiring formed on the insulator; and

20 at least a part of the pair of lead frames, the insulator and the semiconductor light-emitting element are sealed with the sealing resin.

18. The semiconductor light-emitting device according to Claim 1, wherein

the base substance is a lead frame having a cup-shaped mount section;

25 the semiconductor light-emitting element is

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disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

the fluorescent substance is filled in the cup-shaped mount section; and

at least a part of the two lead frames, the semiconductor light-emitting element and the fluorescent substance are sealed with a sealing resin.

19. The semiconductor light-emitting device according to Claim 3, wherein

the base substance is a lead frame having a cup-shaped mount section;

the semiconductor light-emitting element is disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

the fluorescent substance is filled in the cup-shaped mount section; and

at least a part of the two lead frames, the semiconductor light-emitting element and the fluorescent substance are sealed with a sealing resin.

20. The semiconductor light-emitting device according to Claim 5, wherein

the base substance is a lead frame having a cup-shaped mount section;

5 the fluorescent substance is filled in the cup-
shaped mount section; and

10 21. The semiconductor light-emitting device according
to Claim 7, wherein

the semiconductor light-emitting element is
15 disposed at the bottom of the cup-shaped mount section of
the lead frame and electrically connected to another lead
frame by wire bonding;

20 at least a part of the two lead frames, the
semiconductor light-emitting element and the fluorescent
substance are sealed with a sealing resin.

25 the ~~base~~ substance is a lead frame having a cup-

shaped mount section;

the semiconductor light-emitting element is disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

the fluorescent substance is filled in the cup-shaped mount section; and

at least a part of the two lead frames, the semiconductor light-emitting element and the fluorescent substance are sealed with a sealing resin.

23. The semiconductor light-emitting device according to Claim 1, wherein

the base substance is a lead frame having a cup-shaped mount section;

the semiconductor light-emitting element is disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

a coating member is filled in the cup-shaped mount section and the fluorescent substance is disposed on the coating member; and

at least a part of the two lead frames, the semiconductor light-emitting element, the coating member and the fluorescent substance are sealed with a sealing resin.

24. The semiconductor light-emitting device according to Claim 3, wherein

the base substance is a lead frame having a cup-shaped mount section;

5 the semiconductor light-emitting element is disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

10 a coating member is filled in the cup-shaped mount section and the fluorescent substance is disposed on the coating member; and

15 at least a part of the two lead frames, the semiconductor light-emitting element, the coating member and the fluorescent substance are sealed with a sealing resin.

25. The semiconductor light-emitting device according to Claim 5, wherein

the base substance is a lead frame having a cup-shaped mount section;

20 the semiconductor light-emitting element is disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

25 a coating member is filled in the cup-shaped mount section and the fluorescent substance is disposed on

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the coating member; and

at least a part of the two lead frames, the semiconductor light-emitting element, the coating member and the fluorescent substance are sealed with a sealing resin.

26. The semiconductor light-emitting device according to Claim 7, wherein

the base substance is a lead frame having a cup-shaped mount section;

the semiconductor light-emitting element is disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

a coating member is filled in the cup-shaped mount section and the fluorescent substance is disposed on the coating member; and

at least a part of the two lead frames, the semiconductor light-emitting element, the coating member and the fluorescent substance are sealed with a sealing resin.

27. The semiconductor light-emitting device according to Claim 9, wherein

the base substance is a lead frame having a cup-shaped mount section;

the semiconductor light-emitting element is

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disposed at the bottom of the cup-shaped mount section of the lead frame and electrically connected to another lead frame by wire bonding;

5 a coating member is filled in the cup-shaped mount section and the fluorescent substance is disposed on the coating member; and

10 at least a part of the two lead frames, the semiconductor light-emitting element, the coating member and the fluorescent substance are sealed with a sealing resin.

28. The semiconductor light-emitting device according to Claim 1, wherein

the base substance is a substrate provided with metallic wiring;

15 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a sealing resin for sealing the semiconductor light-emitting element is included; and

20 the sealing resin contains the fluorescent substance.

29. The semiconductor light-emitting device according to Claim 3, wherein

25 the base substance is a substrate provided with metallic wiring;

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the semiconductor light-emitting element is electrically connected the metallic wiring on the substrate;

5 a sealing resin for sealing the semiconductor light-emitting element is included; and

the sealing resin contains the fluorescent substance.

30. The semiconductor light-emitting device according to Claim 5, wherein

10 the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected the metallic wiring on the substrate;

15 a sealing resin for sealing the semiconductor light-emitting element is included; and

the sealing resin contains the fluorescent substance.

31. The semiconductor light-emitting device according to Claim 7, wherein

20 the base substance is a substrate provided with metallic wiring;

25 the semiconductor light-emitting element is electrically connected the metallic wiring on the substrate;

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a sealing resin for sealing the semiconductor light-emitting element is included; and

the sealing resin contains the fluorescent substance.

5 32. The semiconductor light-emitting device according to Claim 9, wherein

the base substance is a substrate provided with metallic wiring;

10 the semiconductor light-emitting element is electrically connected the metallic wiring on the substrate;

a sealing resin for sealing the semiconductor light-emitting element is included; and

15 the sealing resin contains the fluorescent substance.

33. The semiconductor light-emitting device according to Claim 1, wherein

the base substance is a substrate provided with metallic wiring;

20 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion; and

the fluorescent substance is filled in the recessed portion.

25 34. The semiconductor light-emitting device according

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to Claim 3, wherein

the base substance is a substrate provided with metallic wiring;

5 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion; and

the fluorescent substance is filled in the recessed portion.

10 35. The semiconductor light-emitting device according to Claim 5, wherein

the base substance is a substrate provided with metallic wiring;

15 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion; and

the fluorescent substance is filled in the recessed portion.

20 36. The semiconductor light-emitting device according to Claim 7, wherein

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion; and

25 the fluorescent substance is filled in the

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recessed portion.

37. The semiconductor light-emitting device according to Claim 9, wherein

the base substance is a substrate provided with
5 metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion; and

the fluorescent substance is filled in the
10 recessed portion.

38. The semiconductor light-emitting device according to Claim 33, wherein

the recessed portion is formed by a frame disposed on the substrate.

39. The semiconductor light-emitting device according to Claim 1, wherein

the base substance is a substrate provided with
15 metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the
20 substrate and disposed in a recessed portion;

a sealing resin is filled in the recessed portion; and

the fluorescent substance is disposed on the
25 sealing resin.

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40. The semiconductor light-emitting device according to Claim 3, wherein

the base substance is a substrate provided with metallic wiring;

5 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion;

a sealing resin is filled in the recessed portion; and

10 the fluorescent substance is disposed on the sealing resin.

41. The semiconductor light-emitting device according to Claim 5, wherein

15 the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion;

20 a sealing resin is filled in the recessed portion; and

the fluorescent substance is disposed on the sealing resin.

42. The semiconductor light-emitting device according to Claim 7, wherein

25 the base substance is a substrate provided with

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the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate and disposed in a recessed portion;

the fluorescent substance is disposed on the
sealing resin.

the base substance is a substrate provided with metallic wiring;

a sealing resin is filled in the recessed portion; and

the fluorescent substance is disposed on the
sealing resin.

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is
25 electrically connected to the metallic wiring on the

substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

5 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

the fluorescent substance is contained in the sealing resin.

10 45. The semiconductor light-emitting device according to Claim 3, wherein

the base substance is a substrate provided with metallic wiring;

15 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

20 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

the fluorescent substance is contained in the sealing resin.

25 46. The semiconductor light-emitting device according

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to Claim 5, wherein

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

the fluorescent substance is contained in the sealing resin.

47. The semiconductor light-emitting device according to Claim 7, wherein

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a sealing resin for sealing the semiconductor

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the fluorescent substance is contained in the
sealing resin.

the base substance is a substrate provided with metallic wiring;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

the fluorescent substance is contained in the
sealing resin.

the base substance is a substrate provided with
metallic wiring;

the semiconductor light-emitting element is
25 electrically connected to the metallic wiring on the

substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

5 a shielding body for shielding light directly emitted from the semiconductor light-emitting element to the outside of the semiconductor light-emitting device is included;

10 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

50. The semiconductor light-emitting device according to Claim 3, wherein

15 the base substance is a substrate provided with metallic wiring;

20 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

25 a shielding body for shielding light directly emitted from the semiconductor light-emitting element to

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the outside of the semiconductor light-emitting device is included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

51. The semiconductor light-emitting device according to Claim 5, wherein

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a shielding body for shielding light directly emitted from the semiconductor light-emitting element to the outside of the semiconductor light-emitting device is included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on

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a surface of the reflector that reflects light.

52. The semiconductor light-emitting device according to Claim 7, wherein

the base substance is a substrate provided with
5 metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

10 a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a shielding body for shielding light directly emitted from the semiconductor light-emitting element to the outside of the semiconductor light-emitting device is
15 included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

20 a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

53. The semiconductor light-emitting device according to Claim 9, wherein

the base substance is a substrate provided with metallic wiring;

25 the semiconductor light-emitting element is

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electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a shielding body for shielding light directly emitted from the semiconductor light-emitting element to the outside of the semiconductor light-emitting device is included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

54. The semiconductor light-emitting device according to Claim 1, wherein

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

at least a light-emitting section of the semiconductor light-emitting element is disposed in a recessed portion in the substrate;

a reflector for reflecting at least a part of

outgoing light from the semiconductor light-emitting element is included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

55. The semiconductor light-emitting device according to Claim 3, wherein

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

at least a light-emitting section of the semiconductor light-emitting element is disposed in a recessed portion in the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

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56. The semiconductor light-emitting device according to Claim 5, wherein

the base substance is a substrate provided with metallic wiring;

5 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

10 at least a light-emitting section of the semiconductor light-emitting element is disposed in a recessed portion in the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

15 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

20 57. The semiconductor light-emitting device according to Claim 7, wherein

the base substance is a substrate provided with metallic wiring;

25 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

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at least a light-emitting section of the semiconductor light-emitting element is disposed in a recessed portion in the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

58. The semiconductor light-emitting device according to Claim 9, wherein

the base substance is a substrate provided with metallic wiring;

the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

at least a light-emitting section of the semiconductor light-emitting element is disposed in a recessed portion in the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

a sealing resin for sealing the semiconductor

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light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the reflector that reflects light.

5 59. The semiconductor light-emitting device according to Claim 1, wherein

the base substance is a substrate provided with metallic wiring;

10 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

15 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the sealing resin that reflects light.

20 60. The semiconductor light-emitting device according to Claim 3, wherein

the base substance is a substrate provided with metallic wiring;

25 the semiconductor light-emitting element is electrically connected to the metallic wiring on the

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substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

5 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the sealing resin that reflects light.

10 61. The semiconductor light-emitting device according to Claim 5, wherein

the base substance is a substrate provided with metallic wiring;

15 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

20 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the sealing resin that reflects light.

25 62. The semiconductor light-emitting device according

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to Claim 7, wherein

the base substance is a substrate provided with metallic wiring;

5 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

10 a sealing resin for sealing the semiconductor light-emitting element and transmitting reflected light from the reflector is included; and

a layer of the fluorescent substance is formed on a surface of the sealing resin that reflects light.

15 63. The semiconductor light-emitting device according to Claim 9, wherein

the base substance is a substrate provided with metallic wiring;

20 the semiconductor light-emitting element is electrically connected to the metallic wiring on the substrate;

a reflector for reflecting at least a part of outgoing light from the semiconductor light-emitting element is included;

25 a sealing resin for sealing the semiconductor

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a layer of the fluorescent substance is formed on a surface of the sealing resin that reflects light.

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the third fluorescent substance has blue outgoing light having emission wavelengths with its main emission peak in a wavelength range of 410 to 480 nm; and

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65. The semiconductor light-emitting device according

to Claim 64, wherein

the first fluorescent substance is composed of any one or more selected from a fluorescent substance group consisting of:

5 M_2O_2S : Eu (M is any one or more elements selected from La, Gd and Y);

$0.5MgF_2 \cdot 3.5MgO \cdot GeO_2$: Mn;

Y_2O_3 : Eu,

$Y(P, V)O_4$: Eu; and

10 YVO_4 : Eu;

the second fluorescent substance is composed of any one or more selected from a fluorescent substance group consisting of:

15 $RMg_2Al_{16}O_{27}$: Eu, Mn (R is any one or both elements selected from Sr and Ba);

$RMgAl_{10}O_{17}$: Eu, Mn (R is any one or both elements selected from Sr and Ba);

ZnS : Cu;

$SrAl_2O_4$: Eu;

20 $SrAl_2O_4$: Eu, Dy;

ZnO : Zn;

$Zn_2Ge_2O_4$: Mn;

Zn_2SiO_4 : Mn; and

25 $Q_3MgSi_2O_8$: Eu, Mn (Q is any one or more elements selected from Sr, Ba and Ca); and

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the third fluorescent substance is composed of any one or more selected from a fluorescent substance group consisting of:

$A_{10}(PO_4)_6Cl_2: Eu$ (A is any one or more elements selected from Sr, Ca, Ba, Mg and Ce);

$XMg_2Al_{16}O_{27}: E$ (X is any one or both elements selected from Sr and Ba);

$XMgAl_{10}O_{17}: Eu$ (X is any one or both elements selected from Sr and Ba);

$ZnS: Ag$;

$Sr_{10}(PO_4)_6Cl_2: Eu$;

$Ca_{10}(PO_4)_6F_2: Sb$;

$Z_3MgSi_2O_8: Eu$ (Z is any one or more elements selected from Sr, Ca and Ba);

$SrMgSi_2O_8: Eu$;

$Sr_2P_2O_7: Eu$;

$CaAl_2O_4: Eu, Nd$.

66. The semiconductor light-emitting device according to Claim 64, wherein, assuming the total amount as 100 weight %,

the first fluorescent substance is between 50 weight % and 70 weight % inclusive;

the second fluorescent substance is between 7 weight % and 20 weight % inclusive; and

the third fluorescent substance is between 20

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weight % and 30 weight % inclusive.

67. The semiconductor light-emitting device according to Claim 66, wherein

the sealing resin contains the first, second and third fluorescent substances; and

the proportion of the total weight of the first, second and third fluorescent substances to the weight of the sealing resin is between 0.5 and 1 inclusive.

68. A light-emitting display device comprising;

a light source using the semiconductor light-emitting device according to Claim 64;

a light guiding plate for guiding light from the light source; and

red, green and blue color filters for transmitting light from the light guiding plate and dividing the light; the light-emitting display device, wherein

outgoing light from the semiconductor light-emitting device has a wavelength distribution that matches spectral characteristics of the color filters.

69. The light-emitting display device according to Claim 68, wherein at least one of the following is adjusted so that the wavelength distribution of the outgoing light from the semiconductor light-emitting device matches spectral characteristics of the color filters:

the emission wavelength of the semiconductor light-emitting element;

the emission wavelength of the first fluorescent substance;

5 the emission wavelength of the second fluorescent substance;

the emission wavelength of the third fluorescent substance;

10 the mixture proportions of the first, second and third fluorescent substances; and

the proportion of the total weight of the first, second and third fluorescent substances to the weight of the sealing resin.

70. The light-emitting display device according to
15 Claim 68, wherein

the light-emitting display device is a liquid crystal display device.

71. The light-emitting display device according to
Claim 69, wherein

20 the light-emitting display device is a liquid crystal display device.

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